

SEMICONDUCTOR®

PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions for all drawings are in inches (mm).
- 2. Tolerance of \pm .010 (.25) on all non-nominal dimensions unless otherwise specified.

FEATURES

- Hermetically sealed package
- Narrow reception angle
- European "Pro Electron" registered

DESCRIPTION

• The BPW36/37 are silicon phototransistors mounted in narrow angle TO-18 packages.



- 1. Derate power dissipation linearly 3.00 mW/°C above 25°C ambient.
- 2. Derate power dissipation linearly 6.00 mW/°C above 25°C case.
- 3. RMA flux is recommended.
- 4. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
- 6. As long as leads are not under any stress or spring tension.
- 7. Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Rating	Unit					
Operating Temperature	T _{OPR}	-65 to +125	°C					
Storage Temperature	T _{STG}	-65 to +150	°C					
Soldering Temperature (Iron) ^(3,4,5 and 6)	T _{SOL-I}	240 for 5 sec	°C					
Soldering Temperature (Flow)(3,4 and 6)	T _{SOL-F}	260 for 10 sec	°C					
Collector-Emitter Voltage	V _{CEO}	45	V					
Collector-Base Voltage	V _{CBO}	45	V					
Emitter-Base Voltage	V _{EBO}	5	V					
Power Dissipation $(T_A = 25^{\circ}C)^{(1)}$	PD	300	mW					
Power Dissipation $(T_C = 25^{\circ}C)^{(2)}$	PD	600	mW					

ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C) (All measurements made under pulse conditions)								
PARAMETER TEST CONDITIONS		SYMBOL	MIN	ТҮР	MAX	UNITS		
Collector-Emitter Breakdown	$I_{\rm C} = 10$ mA, Ee = 0	BVCEO	45	_	_	V		
Emitter-Base Breakdown	I _E = 100 μA, Ee = 0	BVEBO	5.0	—	_	V		
Collector-Base Breakdown	$I_{\rm C} = 100 \ \mu A, \ {\rm Ee} = 0$	ВУсво	45	_	_	V		
Collector-Emitter Leakage	$V_{CE} = 10 \text{ V}, \text{ Ee} = 0$	ICEO		_	100	nA		
Reception Angle at 1/2 Sensitivity		θ		±10		Deg.		
On-State Collector Current BPW36	$Ee = 0.5 \text{ mW/cm}^2$	Lauran	1.0	_	—	mA		
	$V_{CE} = 5 V^{(7)}$	IC(ON)						
On-State Collector Current BPW37	$Ee = 0.5 \text{ mW/cm}^2$	Lauran	0.5	_		mA		
	$V_{CE} = 5 V^{(7)}$	IC(ON)						
Turn-On Time	$I_{\rm C} = 2$ mA, $V_{\rm CC} = 10$ V		_	8	_	μs		
	$R_L = 100 \ \Omega$	t _{on}						
Turn-Off Time	$I_{\rm C} = 2$ mA, $V_{\rm CC} = 10$ V		_	7	_	μs		
	$R_L = 100 \ \Omega$	Loff						
Saturation Voltage	$I_{\rm C} = 1.0 \text{ mA}, \text{ Ee} = 3.0 \text{ mW/cm}^2$	V _{CE(SAT)}		_	0.40	V		

TYPICAL PERFORMANCE CURVES

FAIRCHILD

SEMICONDUCTOR®



Fig. 1 Light Current vs. Collector to Emitter Voltage



Fig. 2 Normalized Light Current vs. Radiation



TYPICAL PERFORMANCE CURVES



Fig. 3 Normalized Light Current vs. Temperature



Fig. 5 Dark Current vs. Temperature



Fig. 4 Switching Times vs. Output Current



Fig. 6 Normalized Light Current vs. Temperature Both Emitter (CQX14) and Detector (BPW36 or BPW37) at Same Temperature



DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body,or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.